

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Patent Application

5 Applicant(s): Fischer et al.
Case: 45-14-2
Serial No.: 10/719,655
Filing Date: November 21, 2003
Group: 2627
10 Examiner: Dismery E. Mercedes

Title: Magnetic Storage Write Heads Using Micro-Electro Mechanical Shutters

15

APPEAL BRIEF

20 Mail Stop Appeal Brief - Patents
Commissioner for Patents
P O. Box 1450
Alexandria, VA 22313-1450

25 Sir:

In response to the Office Action, dated May 11, 2007, Applicants hereby request to reinstate the appeal. Thus, Appellants appeal the rejection dated May 11, 2007, of claims 1 through 20 of the above-identified patent application.

30

REAL PARTY IN INTEREST

The present application is assigned to Agere Systems Inc., as evidenced by an assignment recorded on March 31, 2004 in the United States Patent and Trademark Office at Reel 015168, Frame 0928. The assignee, Agere Systems Inc., is the real party in interest.

RELATED APPEALS AND INTERFERENCES

There are no related appeals or interferences

STATUS OF CLAIMS

5 Claims 1 through 20 are presently pending in the above-identified patent application. Claims 1-20 are rejected under 35 U.S.C. §112, first paragraph, as failing to comply with the enablement requirement. Claims 1-20 are rejected under 35 U.S.C. §103(a) as being unpatentable over Crue et al. (United States Patent Number 6,693,768) in view of Tamura et al (United States Patent No. 6,812,055). Claims 1-20 are being appealed.

10

STATUS OF AMENDMENTS

There have been no amendments filed subsequent to the present rejection

SUMMARY OF CLAIMED SUBJECT MATTER

15 Independent claim 1 is directed to a magnetic storage system, comprising: at least one write coil (110) to generate a magnetic field (120) for at least a plurality of bit intervals (page 3, lines 5-8); a magnetic storage medium (150); and at least one shutter (200) to selectively allow said magnetic field to alter a magnetic domain of said magnetic storage medium (page 3, lines 16-25; page 4, lines 16-18; page 5, lines 13-22).

20 Independent claim 10 is directed to a method for recording information in a magnetic storage medium, said method comprising the steps of: generating a magnetic field for at least a plurality of bit intervals (page 3, lines 5-8); and selectively allowing said magnetic field to alter a magnetic domain of said magnetic storage medium for each bit interval by utilizing a shutter (page 3, lines 16-25; page 4, lines 16-18; page 5, lines 13-22).

25 Independent claim 14 is directed to a write head for a magnetic storage system, comprising: at least one write coil to generate a magnetic field for at least a plurality of bit

intervals (page 3, lines 5-8); and at least one shutter to selectively allow said magnetic field to alter a magnetic domain of a magnetic storage medium (page 3, lines 16-25; page 4, lines 16-18; page 5, lines 13-22).

5 STATEMENT OF GROUNDS OF REJECTION TO BE REVIEWED ON APPEAL

Claims 1-20 are rejected under 35 U.S.C. §112, first paragraph, as failing to comply with the enablement requirement. Independent claims 1, 10, and 14 are rejected under 35 U.S.C. §103(a) as being unpatentable over Crue et al. in view of Tamura et al.

10 ARGUMENT

Section 112 Rejection of Claims 1-20

15 The Examiner asserts that the Specification does not address the claim limitation “a shutter to selectively allow said magnetic field to alter a magnetic domain of said magnetic storage medium,” how the shutter is controlled “so as to selectively allow or inhibit the path of the magnetic field to alter the magnetic domain of the magnetic storage medium,” or “how the medium is attached and how the medium behaves when it is allowing or inhibiting the magnetic flux of the write coil.” The Examiner further asserts that the “descriptions are insufficient for one of ordinary skill in the art to understand how is this ‘shutter’ working in the head in order to selectively allow the magnetic field to alter this magnetic domain.”

20 As indicated in the above summary section, the specification describes in FIG. 2 and the corresponding text a shutter (200) to selectively allow said magnetic field to alter a magnetic domain of said magnetic storage medium (page 3, lines 16-25; page 4, lines 16-18; page 5, lines 13-22).

25 As indicated in Appellants’ prior responses, Appellants do not allege to have invented a shutter system. In fact, shutters were well known to those of ordinary skill in the art at the time the present application was filed. MEMS shutter arrays were available commercial

products at the time the application was filed. See, for example,
<http://www.electronicproducts.com/ShowPage.asp?SECTION=3700&PRIMID=&FileName=sepOL1.sep2003> (describing a MEMS-based light manipulation technology for display and other light manipulation applications), attached as an Exhibit hereto. Please note the date tag in the
5 URL of September 2003 and the present filing date of November 2003. This commercial shutter array is a matrix of "flipping pixels" that can be opened or closed to allow light through. The documentation associated with such a commercial shutter system would clearly describe how to open or close the shutter.

10 The Examiner asserts that Appellants do not "specify under which conditions the 'shutter' is activated or enabled to selectively allow or block the magnetic field." Appellants submit that the specific conditions under which the shutter is activated or enabled to selectively allow or block the magnetic field is a design choice, influenced by the particular shutter selected. The composition of the shutter is addressed further below.

15 The present invention is directed to selectively altering the magnetic domain of a magnetic storage material 150 by controlling the path of a magnetic field 120 *using* one or more shutters 200. In the disclosed magnetic storage system of the present invention, a person of ordinary skill in the art would understand, based on the present disclosure and the commercial availability of such shutter arrays, how to open or close the shutter to selectively allow a magnetic field to alter a magnetic domain of the magnetic storage medium.

20 In this regard, the present specification teaches:

25 In an open position of the shutter 200, the magnetic field 120 is allowed to pass the shutter 200 and will follow an outer loop 130 comprised of magnetic material segments 132, 134, 136 and the magnetic storage material 150. In a closed position of the shutter 200, the magnetic field 120 is not allowed to pass the shutter 200 and will follow an inner loop 140 that bypasses the disk 150 and is comprised of magnetic material segments 132, 134, 136 and 138. In this manner, the magnetic domain of the magnetic storage medium 150 is selectively altered based on the position of

the shutter 200
(Original Specification, at page 3, lines 18-24)

FIG. 2, and the corresponding text on page 4 of the specification, illustrate an exemplary shutter array 200. In this regard, the present specification teaches how the shutter array is *constructed* and how it *operates*:

As shown in FIG. 2, each shutter element 210 can *pivot across a central axis* between an open (not shown) and closed position (shown), in a *similar manner to a venetian blind*. The position of each shutter element 210 can be *controlled*, for example, *using micro electro mechanical systems (MEMS) or other micromachine control elements*. It is noted that micro electro mechanical systems switches are **increasingly used** for optical networks and other applications. In an optical network application, MEMS switches have been employed, for example, to move a mirror that changes the propagation direction of light, or blocks the light entirely. United States Patent Number 5,974,207, for example, discloses a wavelength-selective add-drop multiplexer that uses movable mirrors to add and/or drop spectral components from a wavelength-division-multiplexed optical signal. *Magnetic shielding may be implemented using Nickel (Ni) metallization or Cobalt (Co) deposition on the shutter mechanisms 210*. In this manner, when the shutter elements 210 are in a closed position, the magnetic field will be reflected to the inner loop 140. (Original Specification, at page 4, lines 3-15; emphasis added.)

Shutter Operation (Behavior)

As indicated in the above passage, MEMS devices were well known and already frequently used for other applications at the time of the filing of the present application. The referenced United States Patent Number 5,974,207 describes using a MEMS-based actuator to move an optical device, such as a mirror, into, and out of, the path of an optical signal. The operation of the shutter for magnetic applications would be obvious to a person of ordinary skill in the art, based on the teachings of the present invention, United States Patent Number 5,974,207, as well as commercially available shutter devices

Thus, contrary to the assertion of the Examiner, the present specification gives clear guidance on how the shutters behave. In the above-described exemplary embodiment, the shutters are mounted in an array, such that they can pivot across a central axis between an open and closed position. The pivoting is controlled using MEMS devices which were very well known to those of ordinary skill in the art at the time of filing, as evidenced by U.S. Patent No. 5,974,207 which was cited in the original filing

Shutter Construction (Shutter Attachment)

Again, in the above-described exemplary embodiment, the shutters are fabricated in an array, such that they can pivot across a central axis between an open and closed position. Such a configuration was very well known to those of ordinary skill in the art at the time of filing. See, for example, the commercial shutter array product referenced above and attached hereto. The pivoting arrangement indicates how the shutters are *attached*.

With regard to the *composition* of the shutters themselves, the original specification teaches that the shutters can be coated with a magnetic shielding, such as Nickel or Cobalt. See page 4, lines 12-13. See also, claims 7-9.

Appellants submit that the claimed subject matter is described in the original specification in such a way as to enable a person of ordinary skill in the art to make and use the invention without undue experimentation. Thus, Appellants respectfully request withdrawal of the rejection of claims 1-20 under 35 U.S.C. §112, first paragraph.

Section 103 Rejection of Independent claims 1, 10, and 14

Independent claims 1, 10, and 14 are rejected under 35 U.S.C. §103(a) as being unpatentable over Crue et al in view of Tamura et al.

Regarding claim 1, for example, the Examiner asserts that Crue teaches at least one write coil to generate a magnetic field for at least a plurality of bit intervals (citing Figs. 2-4; 44); and a magnetic storage medium (Fig. 1; 16). The Examiner notes that Crue alters the magnetic domains of the magnetic medium by changing the direction of the magnetic field, but

acknowledges that Crue *fails to specifically disclose* at least one shutter to selectively allow said magnetic field to alter a magnetic domain of said magnetic storage medium.

Appellants note that Crue teaches that

5 *changing the direction of current* changes the direction of flux created by the recording head, and therefore changes the magnetic fields within the magnetic storage medium. A binary "0" is recorded by maintaining a constant direction of magnetic flux through the main pole, and a binary "1" is recorded by *changing* the direction of magnetic flux through the main pole.
10 (Col. 3, lines 36-42; emphasis added.)

15 The present invention energizes a write coil for at least a plurality of bit intervals. The path of the magnetic field is controlled by one or more **shutters** to *selectively* alter the magnetic domain of a magnetic storage material. The Examiner asserts that Tamura et al. discloses a MEMS device comprising a shutter to block or allow the signal level by placing a
20 shutter into and out of the *optical* path (citing col. 18, lines 35-67; emphasis added). The Examiner asserts that the motivation for such a combination is to provide a device that selectively generates displacement forces (citing col. 1, lines 23-25). Appellants are at a loss to understand how the provision of a device that selectively generates "displacement forces" motivates the present invention.

25 Appellants respectfully submit that the Examiner has failed to establish a *prima facie* case of obviousness for at least the reason that there exists no motivation to combine the references, and further, even if combinable, the references collectively do not teach each and every limitation of the independent claims. See, M.P.E.P. §2143.

30 Appellants submit that there is no suggestion to combine the *magnetic* storage system of Crue with the *optical* shutter system of Tamura, other than the hindsight provided by the present invention.

35 In addition, even if combined, the combination does not disclose or suggest a shutter to selectively allow said **magnetic field** to alter a magnetic domain of said magnetic

storage medium. Crue does not disclose a shutter at all (as acknowledged by the Examiner) and the shutter of Tamura alters an *optical* signal

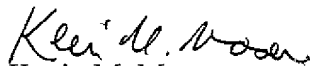
Thus, Crue et al. and Tamura et al., alone or in combination, do not disclose or suggest at least one shutter to selectively allow said magnetic field to alter a magnetic domain of said magnetic storage medium, as required by independent claims 1 and 14, and do not disclose or suggest selectively allowing said magnetic field to alter a magnetic domain of said magnetic storage medium by utilizing a shutter, as required by independent claim 10.

Claims 2-9, 11-13 and 15-20 are dependent on independent claims 1, 10 and 14, respectively and are therefore patentably distinguished over Crue et al. and Tamura et al. because of their dependency from independent claims 1, 10 or 14 for the reasons set forth above, as well as other elements these claims add in combination to their base claim.

Thus, Appellants respectfully request withdrawal of the rejection of claims 1-20 under 35 U.S.C. §103.

The attention of the Examiner and the Appeal Board to this matter is appreciated.

Respectfully,



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Date: August 13, 2007

APPENDIX

1. A magnetic storage system, comprising:
 - at least one write coil to generate a magnetic field for at least a plurality of bit
 - 5 intervals;
 - a magnetic storage medium; and
 - at least one shutter to selectively allow said magnetic field to alter a magnetic domain of said magnetic storage medium.
- 10 2. The magnetic storage system of claim 1, further comprising at least one magnetic pole segment to provide a loop between said at least one write coil and said magnetic storage medium
3. The magnetic storage system of claim 1, comprising a first write coil to generate a positive
- 15 magnetic field, a second write coil to generate a negative magnetic field, and at least two shutters to selectively allow said positive or negative magnetic fields to alter said magnetic domain of said magnetic storage medium.
4. The magnetic storage system of claim 3, wherein said positive or negative magnetic fields
- 20 alter said magnetic domain in a collocated region of said magnetic storage medium.
5. The magnetic storage system of claim 3, further comprising a first set of magnetic pole segments to provide a first loop between said first write coil and said magnetic storage medium and a second set of magnetic pole segments to provide a second loop between said second write
- 25 coil and said magnetic storage medium.

6. The magnetic storage system of claim 1, wherein a position of said shutter is adjusted using a micro-electro mechanical system.

5 7. The magnetic storage system of claim 1, wherein at least one of said shutters is coated with a magnetic shielding.

8. The magnetic storage system of claim 7, wherein said magnetic shielding is comprised of Nickel.

10 9. The magnetic storage system of claim 7, wherein said magnetic shielding is comprised of Cobalt.

10. A method for recording information in a magnetic storage medium, said method comprising the steps of:

15 generating a magnetic field for at least a plurality of bit intervals; and
 selectively allowing said magnetic field to alter a magnetic domain of said magnetic storage medium for each bit interval by utilizing a shutter.

20 11. The method of claim 10, further comprising the steps of generating a positive magnetic field and a negative magnetic field, and selectively allowing said positive or negative magnetic fields to alter said magnetic domain of said magnetic storage medium.

12. The method of claim 11, wherein said positive or negative magnetic fields alter said magnetic domain in a collocated region of said magnetic storage medium.

25 13. The method of claim 10, wherein said step of selectively allowing said magnetic field to alter

a magnetic domain is performed by at least one shutter and said method further comprises the step of adjusting a position of said shutter using a micro-electro mechanical system.

- 5 14. A write head for a magnetic storage system, comprising:
at least one write coil to generate a magnetic field for at least a plurality of bit intervals; and
at least one shutter to selectively allow said magnetic field to alter a magnetic domain of a magnetic storage medium.

10

15 15. The write head of claim 14, further comprising at least one magnetic pole segment to provide a loop between said at least one write coil and said magnetic storage medium.

16. The write head of claim 14, comprising a first write coil to generate a positive magnetic field,
15 a second write coil to generate a negative magnetic field, and at least two shutters to selectively allow said positive or negative magnetic fields to alter said magnetic domain of said magnetic storage medium

17. The write head of claim 16, wherein said positive or negative magnetic fields alter said
20 magnetic domain in a collocated region of said magnetic storage medium.

18. The write head of claim 16, further comprising a first set of magnetic pole segments to provide a first loop between said first write coil and said magnetic storage medium and a second set of magnetic pole segments to provide a second loop between said second write coil and said
25 magnetic storage medium.

19. The write head of claim 14, wherein a position of said shutter is adjusted using a micro-electro mechanical system.

20. The write head of claim 14, wherein at least one of said shutters is coated with a magnetic
5 shielding.

EVIDENCE APPENDIX

The following evidence has been relied on in the above argument:

5

Exhibit 1:

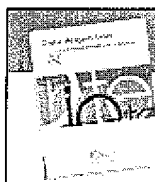
[http://www.electronicproducts.com/ShowPage.asp?SECTION=3700&PRIMID=](http://www.electronicproducts.com/ShowPage.asp?SECTION=3700&PRIMID=&FileName=sepOL1.sep2003)
&FileName=sepOL1.sep2003 (describing a MEMS-based light manipulation technology for
display and other light manipulation applications)

10

United States Patent Number 5,974,207

RELATED PROCEEDINGS APPENDIX

There are no known decisions rendered by a court or the Board in any proceeding identified pursuant to paragraph (c)(1)(ii) of 37 CFR 41.37.



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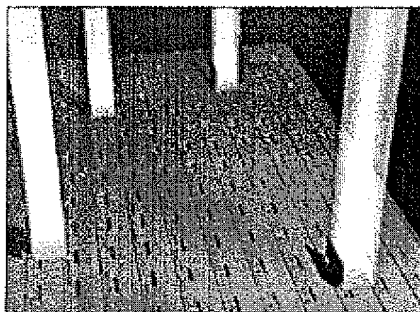
MEMS shutter array to revolutionize optoelectronics

Flipping-pixel matrix can be used in display, optical sensor, lab-on-chip, and light modulation applications

A MEMS-based light manipulation technology called a Flixel Shutter Array promises to create new opportunities in display and other light manipulation applications. The technology has the capacity for superior image contrast and light output at lower system costs compared with any competitive technology.

The Flixel Shutter Array (FSA) by Flixel (Tel Aviv, Israel) is a dense matrix of individually addressable shutters or "flipping pixels" that can be opened or closed 90° or 180° on a stress- and friction-free hinge to allow light through or reflect it back to its source. Deployable in a manner similar to that of an LCD, an FSA has advantages that include the ability to operate without polarized light and with significantly higher transmission efficiency.

The technology supports the creation of smaller and more-efficient high-contrast projection, near-eye, and direct-view displays, as its design enables the use of simpler optics and less light to create a high-quality image at lower system costs than other light-manipulating technologies. FSAs can also be used in optical sensors and other applications requiring controlled modulation of light from ambient or artificial sources.



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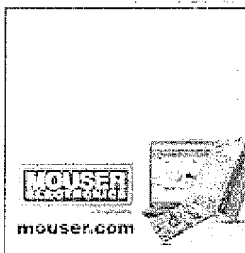
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The Flixiel Shutter Array is a dense matrix of "flipping pixels" that can be opened or closed to allow light through.

Additional FSA benefits include a wide viewing angle and extremely high contrast, due to the on/off gate aspect of the technology, and high light throughput and collection efficiency. Response time is less than 1 μ s, and shutter-operating lifetime exceeds 1 billion actuations, with an added advantage in that a shutter does not require any power to maintain position.

An FSA display can be constructed with a fill ratio of up to 90% and current image resolution can reach as high as 1,200 dpi using 20- μ m shutters. The electrostatically controlled device has an actuation energy equivalent to that of a picofarad-sized capacitor, and operates over a temperature range from -40° to 125°C. For more information, contact Jephtah Lorch of Flixiel at 011-972-3-562-9505, e-mail him at jephtah@flixiel.com, or visit <http://www.flixiel.com>.

-- Alix L. Paultre

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